Silicon Tuning Diode

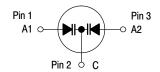
This device is designed for FM tuning, general frequency control and tuning, or any top-of-the-line application requiring back-to-back diode configurations for minimum signal distortion and detuning.

- High Figure of Merit Q = 140 (Typ) @ $V_R = 3.0$ Vdc, f = 100 MHz
- Guaranteed Capacitance Range 37–42 pF @ V_R = 3.0 Vdc (MV104)
- Dual Diodes Save Space and Reduce Cost
- Monolithic Chip Provides Near Perfect Matching Guaranteed ± 1.0% (Max) Over Specified Tuning Range

MAXIMUM RATINGS (EACH DIODE)						
Rating	Symbol	Value	Unit			
Reverse Voltage	V _R	32	Vdc			
Forward Current	١ _F	200	mAdc			
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	280 2.8	mW mW/°C			
Junction Temperature	TJ	+125	°C			
Storage Temperature Range	T _{stg}	-55 to +150	°C			

DUAL VOLTAGE VARIABLE CAPACITANCE DIODE

MV104



CASE 29-11, STYLE 15 TO-92 (TO-226AA)

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μAdc)	V _{(BR)R}	32	—	—	Vdc
Reverse Voltage Leakage Current $T_A = 25^{\circ}C$ $(V_R = 30 \text{ Vdc})$ $T_A = 60^{\circ}C$		_	_	50 500	nAdc
Diode Capacitance Temperature Coefficient ($V_R = 4.0 \text{ Vdc}, f = 1.0 \text{ MHz}$)	TC _C	—	280	—	ppm/°C

	C _T , Diode Capacitance V _R = 3.0 Vdc, f = 1.0 MHz pF		Q, Figure of Merit V _R = 3.0 Vdc f = 100 MHz		C _R , Capacitance Ratio C ₃ /C ₃₀ f = 1.0 MHz	
Device	Min	Max	Min	Тур	Min	Max
MV104	37	42	100	140	2.5	2.8

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MV104

TYPICAL CHARACTERISTICS (Each Diode)

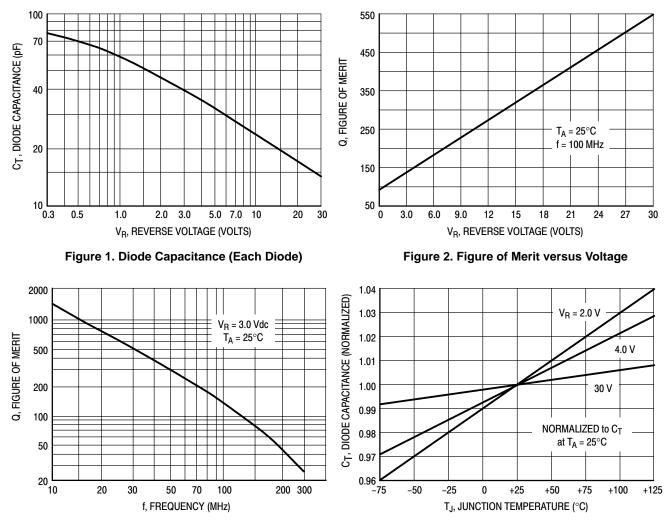


Figure 3. Figure of Merit versus Frequency



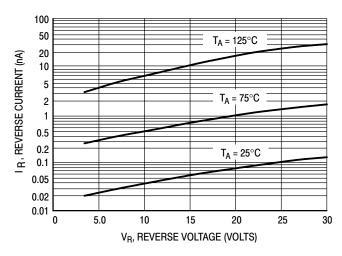
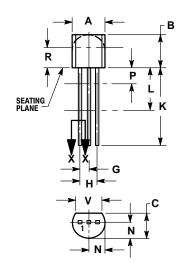


Figure 5. Reverse Current versus Reverse Voltage

MV104

PACKAGE DIMENSIONS

TO-92 (TO-226AA) CASE 29-11 ISSUE AL





YLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
К	0.500		12.70		
L	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Ρ		0.100		2.54	
R	0.115		2.93		
V	0.135		3.43		

MV104

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